APR 2 4 2002

.Sheet 1 of 4

FORM PTO-1449 (REV. 6-89)		U.S. DEPARTMENT OF COMMERCE Patent and Trademark Office		Attorney's Docket No. 21153-05920		Serial No. 10/020,572		
INFORMATION DISCLOSURE				TION	Applicant Sol P. DiJaili			
		(Use several sheets if nec	cessary)	•	Filing Date December 14	Group Art Unit 3662		
-			U.S. PA	TENT DOC	/	·		
Examiner Initial		Document Number	r Date		Name	Class	Subclass	Filing Date If Appropriate
Urne	Α	6,335,992 B1	1-1-02	E	Bala, et al.	385	17	2-15-00
	В	6,333,799 B1	12-25-01	8	Bala, et al.	359	128	1-6-98
	С	6,317,531 B1	11-13-01	С	hen, et al.	385	17	
	D	6,128,115	10-3-00		Shiragaki	359	128	
	E	6,115,517	9-5-00	Shi	ragaki, et al.	385	24	
	F	6,061,156	5-9-00	Tak	eshita, et al.	359	117	
	G	5,999,293	12-7-99		Manning	359	139	
	Н	5,771,320	6-23-98		Stone	385	16	
	i	5,748,653	5-5-98	Pa	Parker, et al.		8	
	J	5,436,759	7-25-95	Di	DiJaili, et al.		333	
	K	5,305,412	4-19-94	Paoli		385	122	
	L	5,299,054	3-29-94		Geiger		251	
	М	4,794,346	12-27-88	,	Miller		4.3	
0	N	3,828,231	8-6-74	Υ	amamoto amamoto	357	30	
TMPU	0	3,467,906	9-16-69	Co	rnely, et al.	330	4.3	•
			• .					
			FOREIGN	PATENT D	OCUMENTS	. 1		
		Document Number	Date		Country	Class	Subclass	Translation Yes No
9MAV	Р	56006492	1-23-81		Japan	H01S	3/18	No
. 1					r, Title, Date, Pertin			
amp	Q	Alcatel, "Alcatel Optro						Press
GMP	·R	Diez, S. et al., "Gain- Photonics Technolog	Transparent	SOA-Switch f	or High-Bitrate OT	DM Add/Dro		ing," <i>IEEE</i>
EXAMINER A	1ar	K Hellner	-	DATE (CONSIDERED 09	107/200	X4.	
		rences considered, whether or n with next communication to appl		formance with MPE	P § 609; Draw line throug	h citation if not in o	conformance an	d not considered.

S	h	26	et	2	O.	f	4

		<u></u>			<u> </u>	neet <u>Z</u> 01 4	
FORM PTO-1449 (REV. 6-89)		U SOEPARTMENT OF COMMERCE attent and Trademark Office	Attomey's Docket No. 21153-05920		Serial No. 10/020,572		
INFORMATION DISCLOSURE CITATION			Applicant Sol P. DiJaili				
		(Use several sheets if necessary)	Filing Date Group Art Unit December 14, 2001 3662				
		U.S. PATENT DOC	UMENTS				
Examiner Initial		Document Number Date	Name	Class	Subclass	Filing Date If Appropriate	
		EODEIGN BATENT D	COLIMENTS	i			
		FOREIGN PATENT D	T	3.	1		
		Document Date Number	Country	Class	Subclass	Translation Yes No	
		Number				165 110	
	•				·		
		OTHER DOCUMENTS (Including Autho	r, Title, Date, Pertinent P	ages, E	tc.)		
m90	S	Diez, S. et al., "Novel Gain-Transparent SOA-Sv ECOC '98, Madrid, Spain (Sept. 1998), pages 40		TDM A	dd/Drop Mu	Itiplexing,"	
		Diez, S. et al., "All-Optical Switch for TDM and V	VDM/TDM Systems De				
		Demultiplexing Experiment," <i>Electronics Letters</i> , Dorgeuille, F. et al., "1.28 Tbit/s Throughout 8/S					
	U	Clamped Semiconductor Optical Amplifier Gates pages 221-223.	•				
		Dorgeuille, F. et al., "Fast Optical Amplifier Gate OFC'98 Technical Digest, pages 42-44.	Array for WDM Routin	ig and S	Switching A	oplications,"	
	W	Doussiere, P. et al., "Clamped Gain Travelling Wave Semiconductor Optical Amplifier for Wavelength Division Multiplexing Applications," Maui, Hawaii, Sept. 19-23, 1994, New York, IEEE, US, Vol. Conf. 14 (9/14/94), pages 185-186.					
		Evankow, JosephD. et al., "Photonic Switching Nournal on Selected Areas in Communications,"					
	Υ	Fernier, B. et al., "Fast (300 ps) Polarization Insection Driving Current (70 mA)," Semiconductor Le	ensitive Semiconductor	r Optica	al Amplifier	Switch With	
	Z	Fjelde, T. et al., "Influence of RZ and NRZ Signa Clamped Semiconductor Optical Amplifiers," Re-	al Format on the High-S	Speed P	Performance	of Gain-	
		Fouquet, J.E. et al., "Compact, Scalable Fiber Optic Cross-Connect Switches," <i>Digest of the LEOS Summer Topical Meetings</i> , San Diego, CA, July 1999, pages 59-60.					
	BB	Ibrahim, Magdy M., "Photonic Switch Using Surf Egypt, Feb. 1999, pages D7 1-D7 8.		de and	APD," NRS	SC '99, Cairo,	
	СС	Jeong, Gibong et al., "Gain Optimization in Swite Journal of Lightwave Technology, Vol. 13, No. 4			r Optical An	nplifiers,"	
9m9J	DD	Kitamura, Shotaro, et al., "Spot-Size Converter I Gate Applications," IBEE Journal of Quantum El	ntegrated Semiconduc	tor Opti			
EXAMINER	Mai		CONSIDERED 09/07	7			
		rences considered, whether or not citation is in conformance with MPE	P § 609; Draw line through citati	on if not in	conformance ar	d not considered.	
Include copy of th	is form w	vith next communication to applicant.					

Sh	neet	3	of	4

FORM PTO-1449 (REV. 6-89)		DEPARTMENT OF COMMERCE PARTIES AND PARTIES		Attorney's Docket No. 21153-05920		Serial No. 10/020,572		
INF	ORN	MATION DISCLOSURE CITATION	ON	Applicant	Sol P. Di)iJaili		
		(Use several sheets if necessary)		Filing Date December 14, 20		Group Art Unit	3662	
		U.S. PATE	ENT DOC					
Examiner Initial		Document Number Date		Name	Class	Subclass	Filing Date If Appropriate	
					-			
						+ +		
		FOREIGN PA	ATENT D	OCUMENTS	1			
		Document Date		Country	Class	Subclass	Translation	
	-	Number		· .			Yes No	
								
	L							
		OTHER DOCUMENTS (Incl	Juding Autho	r, Title, Date, Pertinent	Pages, Et	 ic.)		
MAU	EE	Koyama, F. et al., "Multiple-Quantum- Monolithically Integrated Waveguide I	n-Well Galn <i>A</i> Lens for Hig	As/GalnAsP Tapered gh-Power Applications	Broad-Ar	rea Amplifie		
		Letters, Vol. 5, No. 8 (August 1993), p Leuthold, Juerg et al., "All-Optical Spa IBEE Journal of Quantum Electronics	ace Switches, Vol. 34, N	es with Gain and Princ Io. 4 (April 1998), pag	ges 622-6	33.		
	GG	Luo, G. et al., "Experimental and The Burning Effects in All-Optical Gain-Cla Technology, Vol. 16, No. 4 (April 1998)	eoretical Ana lamped EDF	alysis of Relaxation-O FA's for WDM Network	Scillation	s and Spec		
	НН	McAdams, Larry R. et al., "Linearizing Techniques and Performance," LEOS	g High Perfo	ormance Semiconduc				
		Mork, J., et al., "Semiconductor Device	nductor Devices for All-Optical Signal Processing: Just How Fast Can They					
	JJ	Mutalik, Venkatesh G. et al., "Analog	Go?," LEOS '99, San Francisco, CA, November 1999, Vol. 2, pages 900-901. Mutalik, Venkatesh G. et al., "Analog Performance of 1310-nm Gain-Clamped Semiconductor Optical Amplifiers," OFC '97 Technical Digest, Thursday 11:15 AM, pages 266-267.					
		Panajotov, K. et al., "Polarisation Swit Topical Meetings, San Diego, CA (Jul	itching In Pro	roton-Implanted VCSE	ELs," Dige		EOS Summer	
		Qiu, B.C. et al., "Monolithically Integra Quantum Well Intermixing," Indium Ph Williamsburg, VA (May 2000), pages	rated Fabrica Phosphide ar 415-418.	ation of 2 x 2 and 4 x and Related Materials,	4 Crossp Conferer	point Switch nce Procee	edings,	
	ММ	Scheuer, J. et al., "Nonlinear On-Swit Surface Emitting Lasers," LEOS '99, \$	itching of Hig San Francis	sco, CA (Nov. 1999), '	Vol. 1, pa	ages 123-12	24.	
CHAN			monstration	Using a Birefringence				
EXAMINER !	Ma			CONSIDERED 09/0-	7/04			
EXAMINER: Initia	al if refere	rences considered, whether or not citation is in conform			ition if not in c	conformance an	d not considered.	
nclude copy of the	is form v	with next communication to applicant.						

PTO-1449 REV: 02/01 O 1 P

APR 2 4 2002

Sheet 4 of 4

FORM PTO-1449 (REV. 6-89) INFORM		Patent and Trademark Office MATION DISCLOSURE CITATION		Attorney's Docket No. 21153-05920		Serial No. 10/020,572			
				Applicant `					
	(Use several sheets if necessary)			Sol P. DiJaili Filing Date Group Art Unit					
				December 24,	2001		3662		
		U.S. I	PATENT DO	CUMENTS					
Examiner Initial		Document Number Date		Name	Class	Subclass	Filing Date If		
							Appropriate		
		FOREIG	N PATENT D	OCUMENTS			•		
		Document Date		Country	Class	Subclass	Translation		
		Number					Yes No		
			•						
		OTHER DOCUMENTS	(Including Autho	or, Title, Date, Pertiner	nt Pages, E	itc.)			
	00	Soulage, G. et al., "Clamped Ga							
PMFIU		Dynamic Range Optical Gate," France, undated, 4 unnumbered	d pages.						
	PP	Tai, Chien et al., "Dynamic Ran Based on Low-Gain Semicondu 4 (April 1996), pages 525-533.							
	QQ	Tiemeijer, L.F. et al., "High-Gair							
		, ,	onitor for Optical Gain Control," IEEE Photonics Technology Letters, Vol. 9, No. 3						
	RR	(March 1997), pages 309-311. Tiemeijer, L.F. et al., "Reduced	Intermodulation	Distrotion in 1300 nr	m Gain-Cl	amped MQ	W Laser		
		Amplifiers," IEE Photonics Tech	nology Letters,	Vol. 7, No. 3 (March	1995), pa	ges 284-28	6.		
\ \	SS	Toptchiyski, Gueorgui et al., "Ti Applications," Journal of Lightwo	me-Domain Mod ave Technology	deling of Semiconduc . Vol. 17. No. 12 (De	ctor Optica c. 1999). i	al Amplitiers pages 2577	s for OTDM -2583		
	ТТ	van Roijen, R. et al., "Over 15 d	B Gain From A	Monolithically Integra	ated Optic	al Switch W	/ith An		
0 01	UU	Amplifier," <i>IEEE Photonics Tec</i> Yoshimoto, N. et al., "Spot-Size							
WHO		Submicrometer Strip Structure," IEEE Photonics Technology Letters, Vol. 10, No. 4 (April 1998), pages							
		510-512.				•			
					370000				
EXAMINER (Mac	k Hellner	DATE	CONSIDERED 09/	07/04				
		rences considered, whether or not citation is in	conformance with MPI	EP § 609; Draw line through o	citation if not in	conformance a	nd not considered.		
morade copy of th	na iúimi (with next communication to applicant.							